



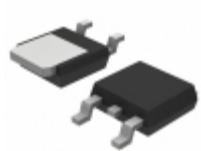

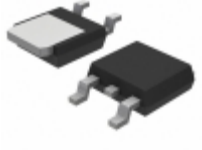
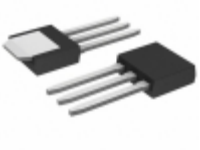
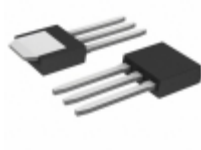
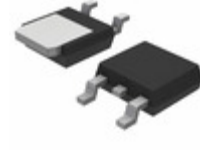
	<h2 style="color: red;">NTDV5805NT4G</h2>
	<p>Hersteller-Teilenummer: NTDV5805NT4G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 40V 51A DPAK</p> <p>Datenblätter:  NTDV5805NT4G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 10000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTDV5805NT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 40V 51A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	10000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	-
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	51A (Tc)
Rds On (Max) @ Id, Vgs	9.5 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	3.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	80nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1725pF @ 25V
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 <p>NTDV20P06LT4G ON ON TO252</p>	 <p>NTDV3055L104T4G ON NTDV3055L104T4G ON</p>	 <p>NTDV20N06T4G-VF01 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A DPAK</p>	 <p>NTDV6414ANT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 32A DPAK</p>
 <p>NTDV2955PT4G AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 12A DPAK</p>	 <p>NTDV2955-1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 12A IPAK</p>	 <p>NTDV3055L104-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 12A IPAK</p>	 <p>NTDV20P06LT4G AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 15.5A DPAK</p>

heiße Teile

Mehr

 NTD70N03	 NTD70N03R	 NTD70N03R-001	 D NTD70N03R-1	 NTD70N03R-1G
 NTD70N03RG	 NTD70N03RT4	 D NTD70N03RT4G	 NTD70N03TR4	 NTD78N03
 NTD78N03-001	 NTD78N03-035	 NTD78N03-1	 NTD78N03-1G	 NTD78N03-35G
 D NTD78N03R-001	 NTD78N03R-1G	 NTD78N03RT4G	 NTD78N03T4	 NTD78N03T4G
 NTD80N02	 NTD80N02-001	 NTD80N02-1	 NTD80N02-1G	 NTD80N02G
 NTD80N02T4	 NTD80N02T4G	 D NTD85N02-1G	 NTD85N02R	 NTD85N02R-001
 NTD85N02R-1	 D NTD85N02R-1G	 NTD85N02R14	 NTD85N02RG	 NTD85N02RT4G
 NTD85N02T4G	 NTD95N02-001	 NTD95N02-1G	 NTD95N02R	 NTD95N02R-1G
 NTD95N02RG	 NTD95N02RT4G	 NTDV18N06LT4G	 D NTDV20N06LT4G	 NTDV20N06T4G
 NTDV20P06LT4G	 NTDV20P06LT4G	 NTDV2955PT4G	 NTDV3055L104T4G	 NTDV5804NT4G

Contact us: Info@Y-IC.com

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